



74LVC3G06

TRIPLE INVERTER WITH OPEN-DRAIN OUTPUTS

Description

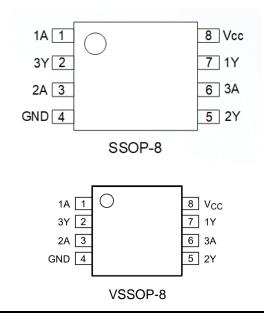
The 74LVC3G06 is a triple inverter with open-drain outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

Each of the inverters performs the positive Boolean function:

$$Y = \overline{A}$$

A pullup resistor is required for a logical HIGH output.

Pin Assignments



Features

Notes:

- Wide Supply Voltage Range from 1.65V to 5.5V
- -24mA Output Drive at 3.3V
- CMOS Low-Power Consumption
- IOFF Supports Partial Power Down Mode Operation
- Inputs Accept up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 2000V Human Body Model (A114)
 Exceeds 1000V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Range of Package Options
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Applications

- Voltage-level shifting
- General-purpose logic
- Power down signal isolation
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks, PDAs
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top boxes
 - · Cell phones, personal navigation / GPS
 - MP3 players, cameras, video recorders

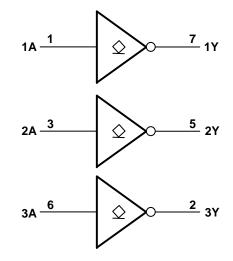
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

^{1.} No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.



Pin Descriptions

Pin Name	Pin NO.	Description		
1A	1	Data Input		
3Y	2	Data Output		
2A	3	Data Input		
GND	4	Ground		
2Y	5	Data Output		
ЗA	6	Data Input		
1Y	7	Data Output		
Vcc	8	Supply Voltage		



Logic Diagram

Function Table

Inputs	Output
Α	Y
Н	L
L	Z

Absolute Maximum Ratings (Notes 4, 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High Impedance or IOFF State	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to 6.5	V
Ік	Input Clamp Current VI < 0	-50	mA
loк	Output Clamp Current V _O < 0	-50	mA
lo	Continuous Output Current	±50	mA
Icc, Ignd	Continuous Current Through V _{CC} or GND	±100	mA
TJ	Junction Temperature	+150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

 Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
 Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range. Notes:



Recommended Operating Conditions (Note 6)

Symbol	Parameter	Conditions	Min	Max	Unit
.,		Operating	1.65	5.5	V
Vcc	Operating Voltage	Data Retention Only	1.5	—	V
		Vcc = 1.65V to 1.95V	0.65 X Vcc	—	
Max	Lich Lovel Input) (oltage	Vcc = 2.3V to 2.7V	1.7	—	v
Vih	High-Level Input Voltage	V _{CC} = 3V to 3.6V	2	_	v
		Vcc = 4.5V to 5.5V	0.7 X Vcc	_	
		V _{CC} = 1.65V to 1.95V	_	0.35 X V _{CC}	
VIL Low-Level Input Voltage		V _{CC} = 2.3V to 2.7V	_	0.7	v
	Low-Level input voltage	V _{CC} = 3V to 3.6V	_	0.8	v
		V _{CC} = 4.5V to 5.5V	_	0.3 X V _{CC}	1
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	—	0	5.5	V
		$V_{CC} = 1.65V$	—	4	
		$V_{CC} = 2.3 V$	—	8	
IOL	Low-Level Output Current	$\lambda = 2\lambda$	—	16	mA
		$V_{CC} = 3V$	_	24	
		$V_{CC} = 4.5 V$	_	32	
		$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$		20	
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate	Vcc = 1.65V to 2.7V		10	ns/\
		$V_{CC} = 2.7 V$ to 5V	—	5	
TA	Operating Free-Air Temperature	_	-40	+125	°C

Note:

6. Unused inputs should be held at V_{CC} or Ground for device proper operation.



Electrical Characteristics

Symbol	Parameter	Test Osmilitiens		-40ºC t	o +85⁰C	-40°C to) +125⁰C	Unit
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
		I _{OL} = 100μΑ	1.65V to 5.5V	-	0.1		0.1	
		IoL = 4mA	1.65V	_	0.45	_	0.45	
Max		IoL = 8mA	2.3V	_	0.3	_	0.3	v
Vol	Low-Level Output Voltage	IoL = 16mA	2)/	_	0.4	_	0.4	V
		IoL = 24mA	3V	_	0.55	_	0.75	
		IoL = 32mA	4.5V	_	0.55	_	0.75	
h	Input Current	VI = 5.5V or GND	0 to 5.5V	_	±5	_	±5	μA
IOFF	Power Down Leakage Current	V_1 or $V_0 = 5.5V$	0	_	±10	_	±10	μA
lcc	Supply Current	$V_1 = 5.5V$ of GND, $I_0 = 0$	1.65V to 5.5V	_	10	_	10	μA
Δlcc	Additional Supply Current	Input at V _{CC} – 0.6V	3V to 5.5V	_	500	_	500	μA
Cı	Input Capacitance	VI = Vcc or GND	3.3V	_	3.5 (Typ)	_	_	pF

Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
0	Thermal Resistance Junction-to-Ambient	SSOP-8	Note 7	—	130	-	°C/W
Θја Τ	Thermal Resistance Junction-to-Ambient	VSSOP-8	Note 7	_	155	_	°C/W
0	Thermal Resistance Junction-to-Case	SSOP-8	Note 7	_	36	_	°C/W
θ _{JC} T	Thermal Resistance Junction-to-Case	VSSOP-8	Note 7	_	38	_	°C/W

Note: 7. Test condition: Device mounted on JEDEC 2s2p High-K board, FR-4 substrate PCB, 2oz copper with minimum recommended pad layout.

Operating Characteristics (T_A = +25°C, V_{CC} = 3.3V)

Symbol	Parameter	Test Conditions	Vcc = 1.8V Typ	Vcc = 2.5V Typ	Vcc = 3.3V Typ	Vcc = 5V Typ	Unit
Cpd	Power Dissipation Capacitance	f = 10MHz, 1 Input Switching	2	2	3	4	pF

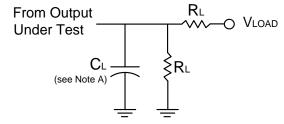
Switching Characteristics

_...

Parameter	From To		V.	T _A = -40°C	T _A = -40°C to +85°C		T _A = -40°C to +125°C	
Input Output	Vcc —	Min	Max	Min	Max	Unit		
tpd A Y		1.8V ± 0.15V	1.8	7.2	1.8	7.8		
	^		2.5V ± 0.2V	1	3.9	1	4.5	
	Ť	3.3V ± 0.3V	1	3.4	1	4.0	ns	
		5.0V ± 0.5V	1	2.9	1	3.5		

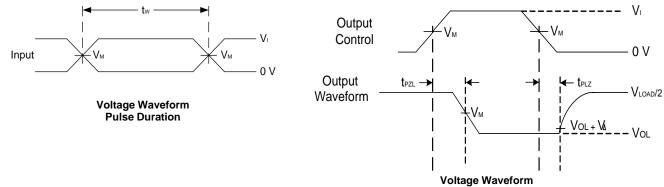


Parameter Measurement Information (Notes B, C)



TEST	Condition
tp∟z (see Notes D and F)	Vload
tpz∟ (see Notes D and E)	Vload

Vcc	Inp	outs	Vм	VLOAD	C∟	R∟	V۵
	VI	tr/tf					
1.8V ± 0.15V	Vcc	≤2ns	Vcc / 2	2 X Vcc	30pF	1kΩ	0.15V
2.5V ± 0.2V	Vcc	≤2ns	Vcc / 2	2 X Vcc	30pF	500Ω	0.15V
3.3V ± 0.3V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
5V ± 0.5V	Vcc	≤2.5ns	Vcc / 2	2 X Vcc	50pF	500Ω	0.3V



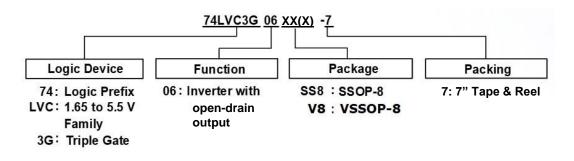
Propagation Delay Times

Figure 1. Load Circuit and Voltage Waveforms

- Notes: A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate \leq 10MHz.
 - C. The inputs are measured one at a time with one transition per measurement.
 - D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD}
 - E. t_{PZL} is measured at V_M.
 - F. t_{PLZ} is measured at V_{OL} +V_{\Delta}.



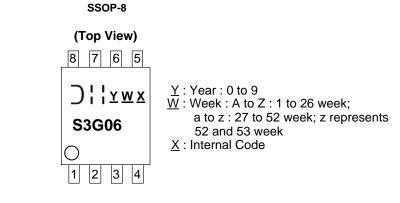
Ordering Information



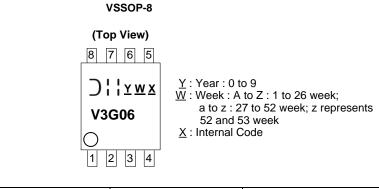
		-	Pac	king
Part Number	Package Code	Package	Qty.	Carrier
74LVC3G06SS8-7	SS8	SSOP-8	3000	7" Tape and Reel (Note 8)
74LVC3G06V8-7	V8	VSSOP-8	3000	7" Tape and Reel (Note 8)

Note: 8. The taping orientation is located on our website at http://www.diodes.com/package-outlines.html.

Marking Information



Part Number	Package	Identification Code
74LVC3G06SS8-7	SSOP-8	S3G06



Part Number	Package	Identification Code
74LVC3G06V8-7	VSSOP-8	V3G06



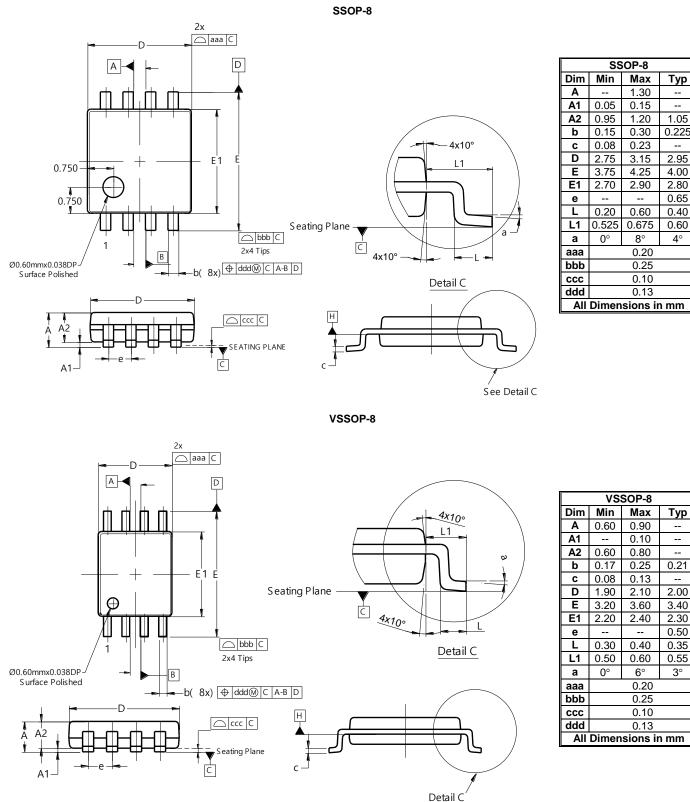
4°

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3°

Package Outline Dimensions

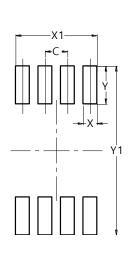
Please see http://www.diodes.com/package-outlines.html for the latest version.





Suggested Pad Layout

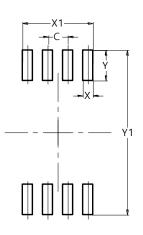
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Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	2.350
Y	1.100
Y1	4.900

VSSOP-8

SSOP-8



Mechanical Data

SSOP-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0169 grams (Approximate)

VSSOP-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.011 grams (Approximate)

74LVC3G06
Document number: DS44929 Rev. 2 - 2

Dimensions	Value (in mm)
С	0.500
Х	0.250
X1	1.750
Y	0.750
Y1	4.050



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